Compton profiles of Si: Pseudopotential calculation and reconstruction effects


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Using an ab initio pseudopotential calculation, we compute Compton profiles of silicon along the (100), (110), and (111) directions, and then reconstruct the pseudo-wave-functions to regain the oscillatory behavior of the all-electron valence wave functions near the atomic cores. We study the effect that this reconstruction has on the Compton profiles and their anisotropies. We find a decrease in the magnitude of the profiles at small wave vectors and in their anisotropies. These changes bring the theoretical predictions closer to experimental results. [S0163-1829(98)03628-5]

I. INTRODUCTION

Compton profiles\(^1\) study the energy profiles of photons that have been Compton scattered from electrons in condensed-matter systems. These profiles give information about the ground-state momentum density of the system, and can serve as a good check on the quality of the wave functions used in theoretical calculations. The differences or anisotropies between Compton profiles along different crystallographic directions are also investigated as they bring out some features hidden in the bell-like profiles. The accuracy with which the energy of the scattered photons can be measured has improved greatly in recent years, and so it is interesting to see if theoretical calculations of the Compton profiles match the more accurate experimental measurements. Many different condensed-matter systems are being studied, but silicon is being focused upon as a test case.\(^2\)

Most older calculations of the Compton profiles of solids had used either tight-binding methods\(^3\) or empirical pseudopotentials\(^4\) to calculate wave functions, form momentum densities, and compute profiles. Both methods have disadvantages: the tight-binding method has parameters that must be chosen, and will not reproduce the wave functions well in interstitial regions, while the pseudo-wave-functions from the empirical pseudopotential calculation have lost the oscillatory behavior that the all-electron wave functions have near the atomic cores. Nevertheless, both methods can predict the profile shape well qualitatively, though it would seem from comparison with experimental data that theoretical calculations tend to overestimate the height of the profiles at low momenta and the size of the anisotropy in the profiles.\(^5\) In recent years, self-consistent calculations have been performed using the Korringa-Kohn-Rostoker (KKR) band-structure scheme\(^6,7\) and the full-potential linearized augmented-plane-wave method (FLAPW),\(^8\) and have compared favorably to recent experiments.

The first part of our work in this paper is to do an ab initio pseudopotential calculation on silicon, using density-functional theory\(^9\) in the local-density approximation,\(^10\) and to use the resulting valence pseudo-wave-functions to calculate the momentum density \(n(p)\) and then the Compton profiles \(J(q)\) along some high-symmetry directions. Then we reconstruct the all-electron valence wave functions from the pseudo-wave-functions by using a scheme devised by Meyer, Hummler, Elsässer, and Fähnle.\(^11\) By this reconstruction, we regain the oscillations in the core regions that were lost in using a pseudopotential in the initial calculation. With the reconstructed wave functions, we again calculate \(n(p)\) and the various \(J(q)\), in order to see if the addition of the core behavior of the wave functions causes any changes in the profiles or their anisotropies.

II. DEFINITIONS

The Compton profile \(J(q)\) along a particular direction is what is directly measured in an experiment. By changing the orientation of the sample in an experiment, different crystallographic directions can be examined. Within the impulse approximation,\(^4\) we can calculate the profile along a direction given by the unit vector \(\hat{e}\) from the formula

\[
J(q) = \int_{\text{all space}} dp n(p) \delta(p \cdot \hat{e} - q).
\]

In other words, for a fixed value of \(q\), we integrate \(n(p)\) over the plane perpendicular to \(\hat{e}\), which cuts the line along \(\hat{e}\) at a signed distance \(q\) from the origin.

Here, \(n(p)\) is the probability density of the momentum of the electrons. In theoretical calculations these may either be just the valence electrons or just the core electrons, or both, while in experimental measurements on silicon both core and valence electrons scatter the photons and so contribute to the profiles. As the expression for the Compton profile is linear in the momentum density, a profile from just the core electrons can be calculated and then subtracted off from the total experimental Compton profile to obtain the valence profile. If we assume that the core electrons are unaffected by the presence of the other atoms in the crystal, then the momentum density of the core electrons will be spherically symmetric, so that the core Compton profiles will be the same along any direction, and will cancel out in the anisotropies. In our calculation, we calculate the momentum density and Compton profiles of the valence electrons only.

We define the valence momentum density \(n(p)\) in such a way that it obeys the normalization
\[ \int_{\text{all space}} d\mathbf{p} n(\mathbf{p}) = 4, \]  
(2)

since silicon has four valence electrons per atom. From this it follows that the Compton profile \( J(q) \) along any direction obeys the normalization

\[ \int_{-\infty}^{+\infty} dq J(q) = 4. \]  
(3)

III. PSEUDOPOTENTIAL CALCULATION

Using density-functional theory in the local-density approximation, we performed an \textit{ab initio} pseudopotential calculation on silicon in the diamond structure. We used a norm-conserving Hamann-Schlüter-Chiang pseudopotential, with cutoff radii of 1.2 a.u., 1.3 a.u., and 1.7 a.u. for the 3s, 3p, and 3d states. In the generation of the pseudopotential, the 3s orbital was fully occupied with two electrons, the 3p orbitals with 1.6 electrons, and the 3d orbitals with 0.4 electrons. A partial core correction was used for the exchange potential.13

The pseudo-wave-functions were expanded in a planewave basis set with an energy cutoff of 15 Ry, at the experimental primitive cell volume of 270.107 a.u. This corresponds to an expansion into approximately 265 plane waves. The Ceperley-Alder electron gas results14 as parametrized by Perdew and Zunger15 were used for the exchange-correlation potential. For \( k \)-space integrations, we used a Monkhorst-Pack16 unshifted \( 30 \times 30 \times 30 \) grid of \( k \) points in the primitive cell of the reciprocal lattice. We calculated the band energies for the lowest eight bands and the pseudo-wave-functions for the four occupied bands self-consistently on the 752 irreducible \( k \) points. This density of \( k \) points gave an effective distance between \( k \) points of 0.033 a.u. This dense grid of \( k \) points was chosen so that a linear interpolation scheme could be used to calculate the momentum density at other points in reciprocal space. Then the momentum density \( n(\mathbf{p}) \) was calculated from the pseudo-wave-functions by unfolding the data from the irreducible \( k \) points into the full Brillouin zone, and then squaring the Fourier coefficients.

The Compton profiles along the cubic (100), (110), and (111) directions were calculated by integration of the momentum density using the linear tetrahedron method.17,18 For each profile, we performed 451 planar integrations of the momentum density, at momentum values between \( q = 0 \) a.u. and \( q = 3.0 \) a.u. Negative \( q \) were not used as the profiles are symmetrical about \( q = 0 \). Integration of each profile from \( -3.0 \) to \(+3.0 \) a.u. gave the expected value of 4.

We checked the convergence of the calculation in the energy cutoff by doing a calculation with a \( 20 \times 20 \times 20 \) grid at both 10 Ry and 20 Ry. The convergence of the \( k \)-point grid was checked by running with an energy cutoff of 10 Ry, and two grid sizes of \( 20 \times 20 \times 20 \) and \( 30 \times 30 \times 30 \). In both cases, the profiles changed by at most 0.3% of the profile height at \( q = 0 \).

IV. RECONSTRUCTION OF THE ALL-ELECTRON VALENCE WAVE FUNCTIONS

The pseudo-wave-functions are constructed so as to have a smooth behavior near to the atomic cores, and so they lack some of the high-momentum Fourier components that the all-electron valence wave functions have. This implies that the momentum density \( n(\mathbf{p}) \) formed from the pseudo-wave-functions will be reduced in weight at high momenta and, by normalization, have too much weight at low momenta. The same tendency will be found in the Compton profiles, although in the anisotropies it may be reduced if the corrections are spherically symmetrical.

To study this effect, we reconstruct the all-electron valence wave functions \( \psi_{\alpha k} \) from the pseudo-wave-functions \( \tilde{\psi}_{\alpha k} \) using a scheme devised by Meyer, Hummler, Elsaßser, and Fähnle.11 As the pseudopotential is constructed so as to give a pseudo-wave-function that reproduces the all-electron wave function outside some cutoff radius, we only have to change the pseudo-wave-functions inside a reconstruction sphere around the atoms, which includes this cutoff radius, and which should also enclose all of the core charge of the atom. Once the radius \( r_{\text{rec}} \) of this reconstruction sphere is chosen, we re-solve the Kohn-Sham equation using an all-electron potential for each valence wave function in the interior of this sphere. The necessary boundary conditions are specified by using the values of the corresponding pseudo-wave-function on the surface of the sphere. Once all of the pseudo-wave-functions have been reconstructed, we recalculate the all-electron potential and iterate to self-consistency.

In the calculation, we choose the reconstruction radius to be \( r_{\text{rec}} = 1.5 \) a.u. At this radius, the \( s \), \( p \), and \( d \) atomic pseudo-wave-functions and the atomic all-electron wave functions are very close to one another, so the use of the crystal pseudo-wave-functions as boundary conditions on the solutions inside the reconstruction sphere is justified. Using these reconstructed wave functions, we recalculate the momentum density. Again, we integrate the momentum density to find the Compton profiles along the three chosen cubic directions.

V. RESULTS AND DISCUSSION

In Fig. 1, we plot the valence momentum density along the (100) direction for both the pseudo-wave-functions and the reconstructed wave functions. By way of comparison, note that for a free Fermi gas with the same electron density, the momentum density would be a spherically symmetric step function, with the step located at the Fermi momentum \( k_F = 0.957 \) a.u. and having a height of 1.09 in the present units. As expected, we see that adding in the oscillations of the valence wave functions in the core regions gives us a noticeable reduction in the momentum density at \( q = 0 \). This lost weight should transfer outwards to higher momenta, and indeed we find that the reconstructed momentum density has a slowly decaying tail. This tail is small in magnitude, but extends far enough out in momentum space to make up for the loss in weight near the origin.

In Figs. 2, 3, and 4, we show the valence Compton profiles along the (100), (110), and (111) directions for the pseudopotential and reconstructed momentum densities, and
compare them with some experimental profiles. The two experiments we compare our profiles with are x-ray Compton profiles with incident photon energies of 29.5 keV (Ref. 5) and 59.38 keV, respectively. The 29.5-keV experiment measured the (100) and (110) profiles, while the 59.38-keV experiment measured these profiles and the (111). In the figures, we display our theoretical results convoluted with the respective experimental resolutions of 0.084 and 0.12 a.u. So, on the left portion (negative q values) of the (100) and (110) graphs we show the comparison with the 29.5 keV experiment, and on the right portion (positive q values) we compare with the 59.38 measurement. For the (111) direction, we have only the 59.38-keV data to compare with.

We see a substantial change in the valence Compton profiles due to the reconstruction procedure. The largest change is near the origin, where there is a reduction in the peak height of approximately 6%. A long-range tail now appears, which compensates for the missing weight in the profile near zero. This tail is also visible in the momentum density in Fig. 1, but due to the planar integration over the momentum density, we have only the 59.38-keV data to compare with.
FIG. 5. The anisotropy between the (100) and (110) Compton profiles, from both the pseudopotential (dashed line) and the reconstruction (solid line) calculations, and also from experimental data at 29.5 keV (Ref. 5) and 59.38 keV (Ref. 19). On the left portion, the 29.5-keV experiment is graphed, with data points indicated by squares. On the right portion are the 59.38-keV data, denoted by triangles. Again, the theoretical profiles are convoluted with the appropriate experimental resolution function. The anisotropies are in units of electrons per atom per atomic unit.

VI. CONCLUSION

We find that the reconstruction of the all-electron valence wave functions from the pseudo-wave-functions substantially changes the valence Compton profiles of silicon along all three of the directions studied, and introduces a tail in the momentum density and profiles that persists to large momenta. Agreement with experiment is substantially improved by the use of the reconstructed wave functions, and we find excellent agreement with the 29.5-keV data. In the anisotropy, the changes in the momentum density caused by the reconstruction procedure are not spherically symmetric, but lead to appreciable changes in the theoretical predictions, in particular for the (100)-(111) anisotropy. These changes bring the theoretical predictions closer to experiment. Because of the differences between the results from the two experiments we use for comparison, it is hard to say which of the remaining discrepancies between theory and experiment arise due to experimental noise or systematic errors, and which are due to inadequacies in theory. We have also compared our theoretical results for the reconstruc- ted valence Compton profiles with FLAPW and KKR calculations for silicon, and we find excellent agreement among all three methods.2 Elsewhere, we will examine further corrections to...
the Compton profiles due to correlation effects between the valence electrons, using a correlated wave-function quantum Monte Carlo approach.

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19 Y. Sakurai (private communication).